

# DTC123Y

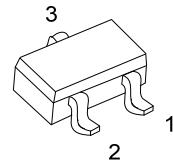
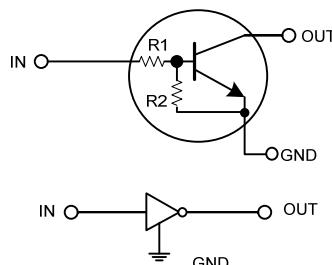
**NPN SILICON TRANSISTOR**

## NPN DIGITAL TRANSISTOR (BUILT-IN BIAS RESISTORS)

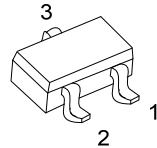
### ■ FEATURES

- \* Built-in bias resistors that implies easy ON/OFF applications.
- \* The bias resistors are thin-film resistors with complete isolation to allow negative input.

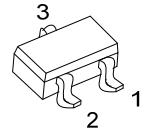
### ■ EQUIVALENT CIRCUIT



SOT-23



SOT-323



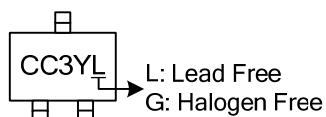
SOT-523

### ■ ORDERING INFORMATION

Ordering Number			Package	Pin Assignment			Packing
Normal	Lead Free	Halogen Free		1	2	3	
DTC123Y-AE3-R	DTC123YL-AE3-R	DTC123YG-AE3-R	SOT-23	G	I	O	Tape Reel
DTC123Y-AL3-R	DTC123YL-AL3-R	DTC123YG-AL3-R	SOT-323	G	I	O	Tape Reel
DTC123Y-AN3-R	DTC123YL-AN3-R	DTC123YG-AN3-R	SOT-523	G	I	O	Tape Reel

 (1)Packing Type (2)Package Type (3)Lead Plating	(1) R: Tape Reel (2) AE3: SOT-23, AL3: SOT-323, AN3: SOT-523 (3) G: Halogen Free, L: Lead Free, Blank: Pb/Sn
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### ■ MARKING



## ■ ABSOLUTE MAXIMUM RATING (Ta=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V <sub>CC</sub>	50	V
Input Voltage		V <sub>IN</sub>	-5 ~ +12	V
Output Current		I <sub>OUT</sub>	100	mA
		I <sub>C(MAX)</sub>	100	mA
Power Dissipation	SOT-23/SOT-323	P <sub>D</sub>	200	mW
	SOT-523		150	mW
Storage Temperature		T <sub>J</sub>	+150	°C
Junction Temperature		T <sub>STG</sub>	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

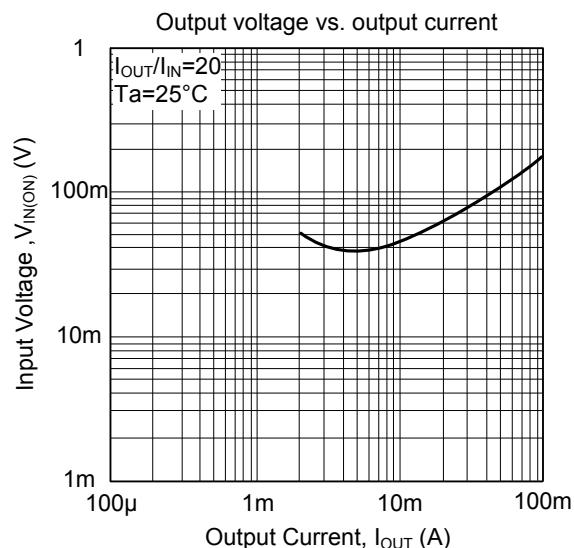
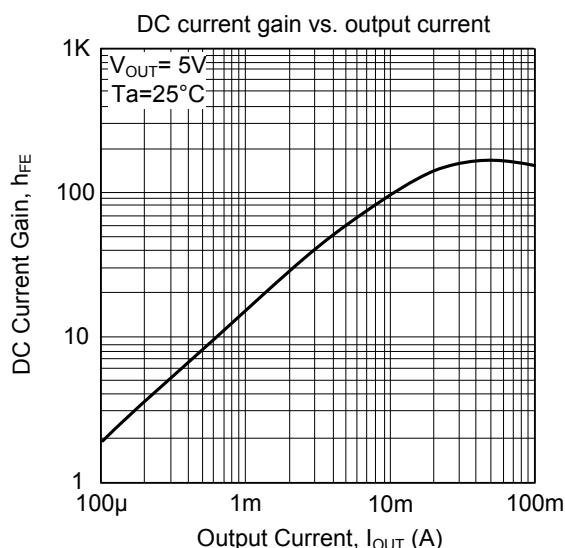
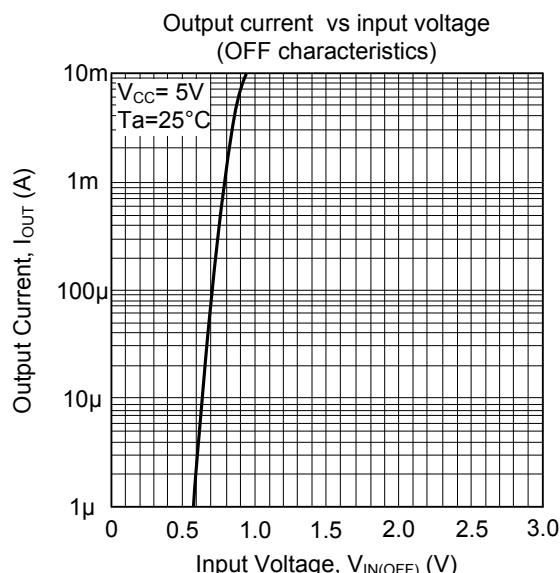
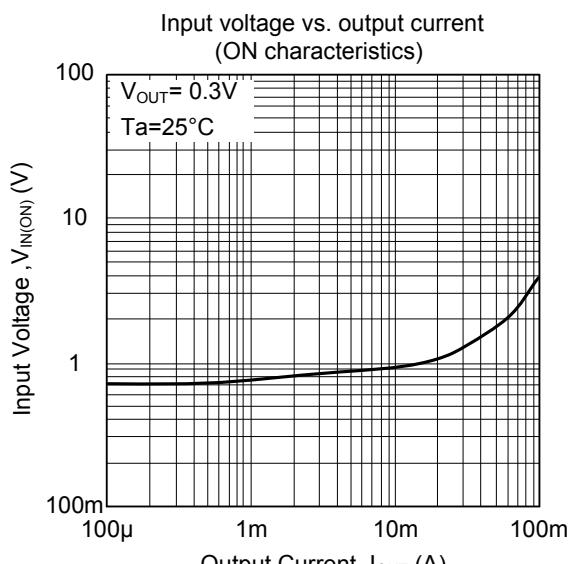
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V <sub>IN(OFF)</sub>	V <sub>CC</sub> =5V, I <sub>OUT</sub> =100µA			0.3	V
	V <sub>IN(ON)</sub>	V <sub>OUT</sub> =0.3V, I <sub>OUT</sub> =20mA	3			V
Output Voltage	V <sub>OUT(ON)</sub>	I <sub>OUT</sub> /I <sub>IN</sub> =10mA/0.5mA		0.1	0.3	V
Input Current	I <sub>IN</sub>	V <sub>IN</sub> =5V			3.8	mA
Output Current	I <sub>OUT(OFF)</sub>	V <sub>CC</sub> =50V, V <sub>IN</sub> =0V			0.5	µA
DC Current Gain	h <sub>FE</sub>	V <sub>OUT</sub> =5V, I <sub>OUT</sub> =10mA	33			
Input Resistance	R <sub>1</sub>		1.54	2.2	2.86	KΩ
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>		3.6	4.5	5.5	
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>E</sub> =-5mA, f=100MHz(Note)		250		MHz

Note: Transition frequency of the device

■ TYPICAL CHARACTERISTICS



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